

## **ISC Silicon NPN Power Transistor**

# 2SC3449

#### **DESCRIPTION**

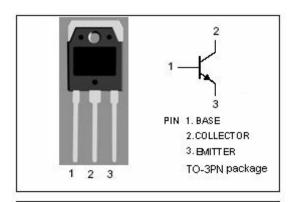
- Low Collector Saturation Voltage
- · High breakdown voltage and high reliability
- Fast switching speed
- Wide ASO
- NPN triple diffused planar silicon transistor
- 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

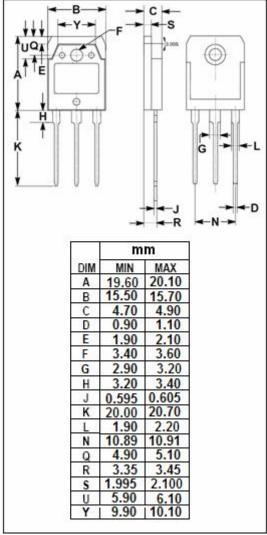


· Switching regulator applications

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>СВО</sub>	Collector-Base Voltage	800	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	500	V	
V <sub>EBO</sub>	Emitter-Base Voltage	7	V	
lc	Collector Current-Continuous	7	А	
Ісм	Collector Current-Pulse	14	Α	
I <sub>B</sub>	Base Current-Continuous	3	Α	
Pc	Collector Power Dissipation @ $T_c$ =25 $^{\circ}$ C	80	W	
TJ	T <sub>J</sub> Junction Temperature		$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	${\mathbb C}$	







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT	
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA ; I <sub>B</sub> = 0	500			V	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.6A			1.0	V	
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.6A			1.5	V	
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 500V; I <sub>E</sub> = 0			10	μА	
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			10	μА	
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.6A; V <sub>CE</sub> = 5V	15		50		
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 5V	8				
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f= 1MHz		80		pF	
f⊤	Current-Gain—Bandwidth Product	I <sub>E</sub> = -600mA; V <sub>CE</sub> = 10V		18		MHz	

#### ♦ h<sub>FE-1</sub> Classifications

L	M	N
15-30	20-40	30-50

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